

## HYBRID INTEGRATED CIRCUIT VHF/UHF WIDE-BAND AMPLIFIER

Three-stage wide-band amplifier in hybrid integrated circuit technique on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in MATV systems, and as general-purpose amplifier for v.h.f. and u.h.f. applications.

### QUICK REFERENCE DATA

Frequency range	$f$	40 to 860 MHz
Source and load (characteristic) impedance	$R_s = R_l = Z_0 =$	75 $\Omega$
Transducer gain	$G_{tr} =  s_f ^2$	typ. 28 dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ. 1 dB
Output voltage at -60 dB intermodulation distortion (DIN 45004, 3-tone)	$V_o(\text{rms})$	> 105 dB $\mu$ V
Noise figure	$F$	typ. 4,4 dB
D.C. supply voltage	$V_B$	= 12 V $\pm$ 10%
Operating ambient temperature	$T_{amb}$	-20 to +70 °C

ENCAPSULATION 8-pin, in-line, resin-coated body, see MECHANICAL DATA (Fig. 2)

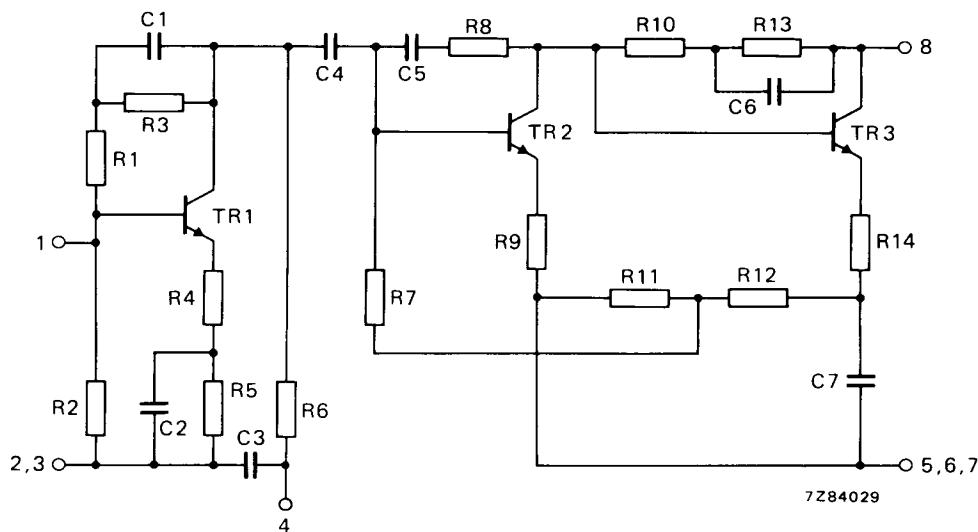


Fig. 1 Circuit diagram.

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Operating ambient temperature	$T_{amb}$	-20 to +70 °C
Storage temperature	$T_{stg}$	-40 to +125 °C
D.C. supply voltage	$V_B$	max. 15 V
Peak incident powers on pins 1 and 8	$P_{11M}, P_{18M}$	max. 100 mW

**CHARACTERISTICS****Measuring conditions**

Ambient temperature	$T_{amb}$	=	25 °C
D.C. supply voltage	$V_B$	=	12 V
Source impedance and load impedance	$R_s, R_L$	=	75 Ω
Characteristic impedance of h.f. connections	$Z_0$	=	75 Ω
Frequency range	f	=	40 to 860 MHz

**Performance**

Supply current	$I_B$	typ.	50 mA
Transducer gain	$G_{tr} =  s_f ^2$	typ.	28 dB 26 to 31 dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1 dB
Individual maximum v.s.w.r.			
input	$VSWR(i)$	typ.	1,5 *
output	$VSWR(o)$	typ.	1,7 *
Back attenuation			
f = 100 MHz	$ s_r ^2$	typ.	45 dB
f = 860 MHz	$ s_r ^2$	typ.	35 dB
Output voltage			
at -60 dB intermodulation distortion (DIN 45004, par. 6.3; 3-tone)	$V_o(rms)$	> typ.	105 dBμV 107 dBμV
Noise figure	F	typ.	4,4 dB

s-parameters:	$s_f = s_{21}$	$s_i = s_{11}$
	$s_r = s_{12}$	$s_o = s_{22}$

\* Highest value, for a sample, occurring in the frequency range.

**OPERATING CONDITIONS**

Ambient temperature range	$T_{amb}$	-20 to +70 °C
D.C. supply voltage	$V_B$	= 12 V ± 10%
Frequency range	$f$	40 to 860 MHz
Source impedance and load impedance	$R_s, R_l$	= 75 Ω

**MECHANICAL DATA**

The device is resin coated.

Dimensions in mm

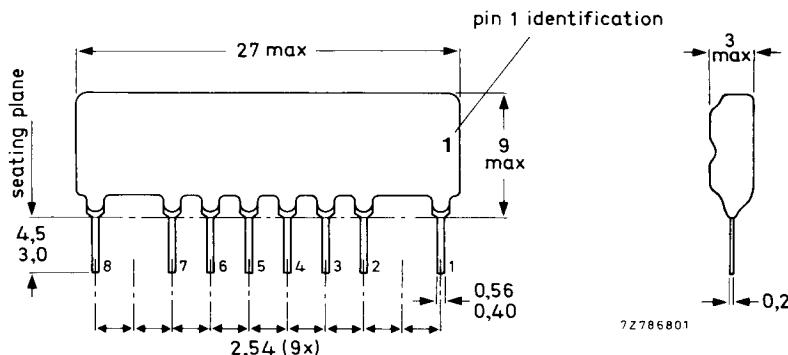


Fig. 2 Encapsulation.

**Terminal connections**

- 1 = input
- 2, 3, 5, 6, 7 = common
- 4 = supply (+)
- 8 = output/supply (+)

**Soldering recommendations***Hand soldering*

Maximum contact time for a soldering-iron temperature of 260 °C up to the seating plane is 5 s.

*Dip or wave soldering*

260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds. The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

**Mounting recommendations**

The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.

Input and output should be connected to  $75\ \Omega$  tracks.

The connections to the 'common' pins should be as close to the seating plane as possible.

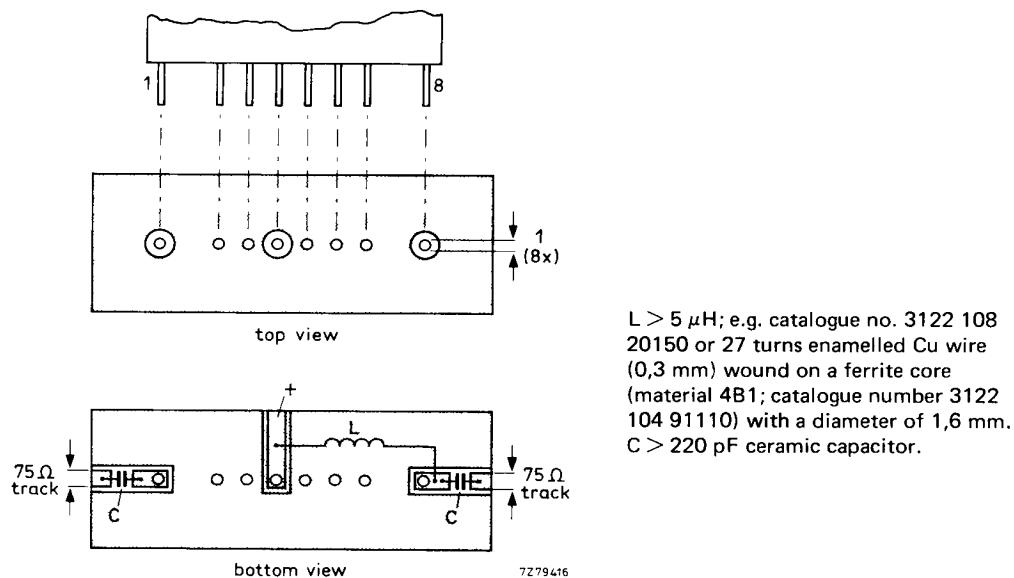


Fig. 3 Printed-circuit board holes and tracks.

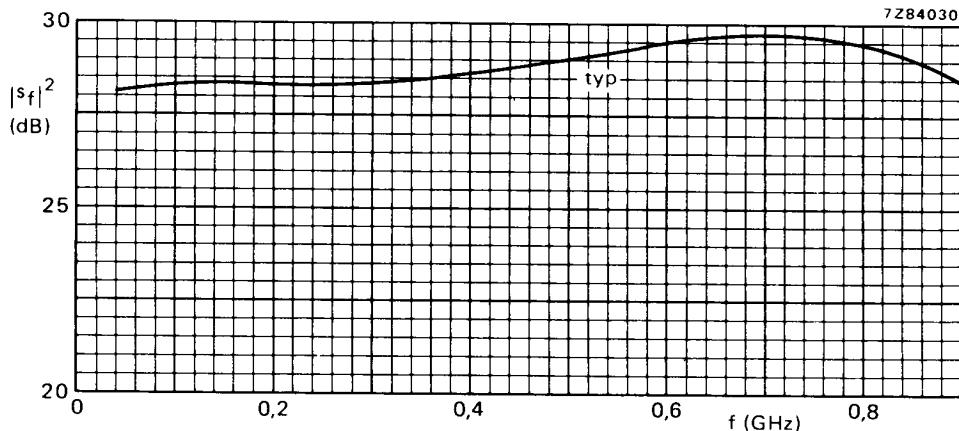


Fig. 4 Transducer gain as a function of frequency;  $Z_0 = 75\ \Omega$ .

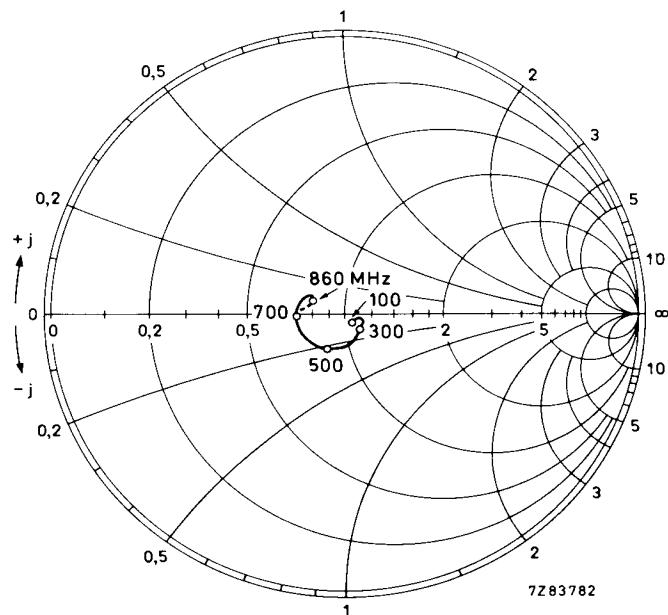


Fig. 5 Input impedance derived from input reflection coefficient  $s_i$ , co-ordinates in ohm  $\times 75$ ; typical values.

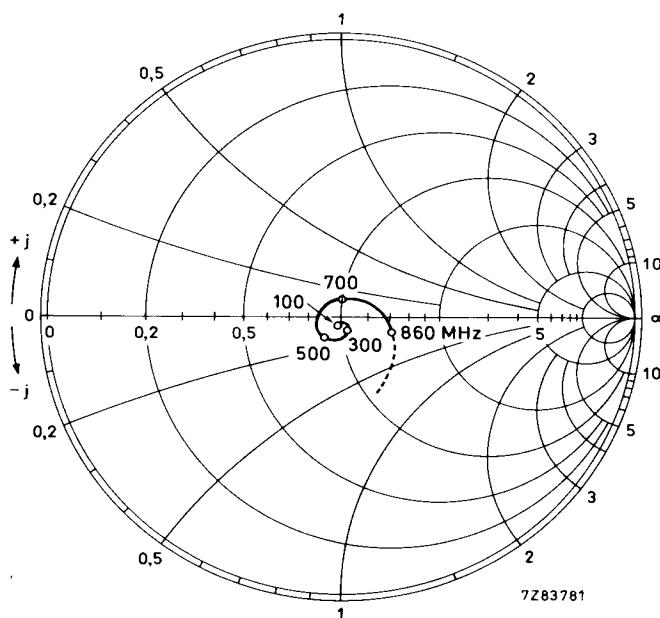


Fig. 6 Output impedance derived from output reflection coefficient  $s_o$ , co-ordinates in ohm  $\times 75$ ; typical values.

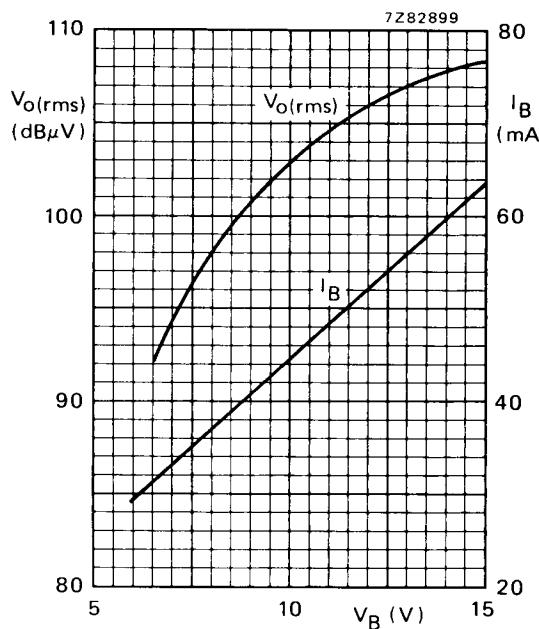


Fig. 7 Output voltage and supply current as a function of the supply voltage; typical values.

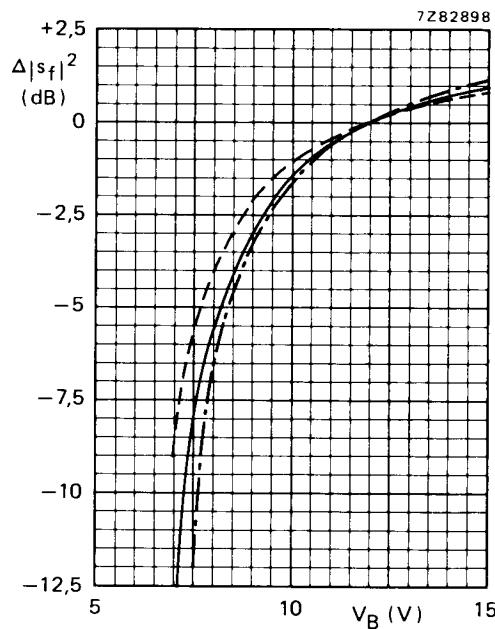


Fig. 8 Variation of transducer gain with supply voltage; reference 0 dB at 12 V;  
 — f = 500 MHz;  
 - - - f = 100 MHz;  
 - · - f = 860 MHz;  
 typical values.